

## Upgrades of the ATLAS inner detector for HL-LHC (pixels)

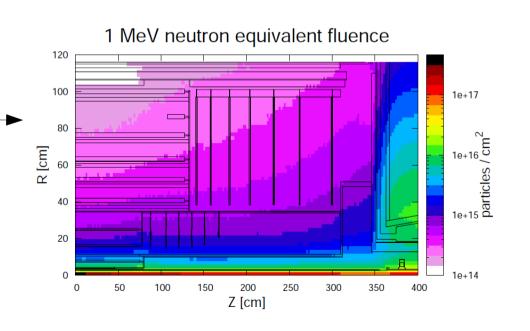
Jörn Grosse-Knetter University of Göttingen

on behalf of the ATLAS Collaboration

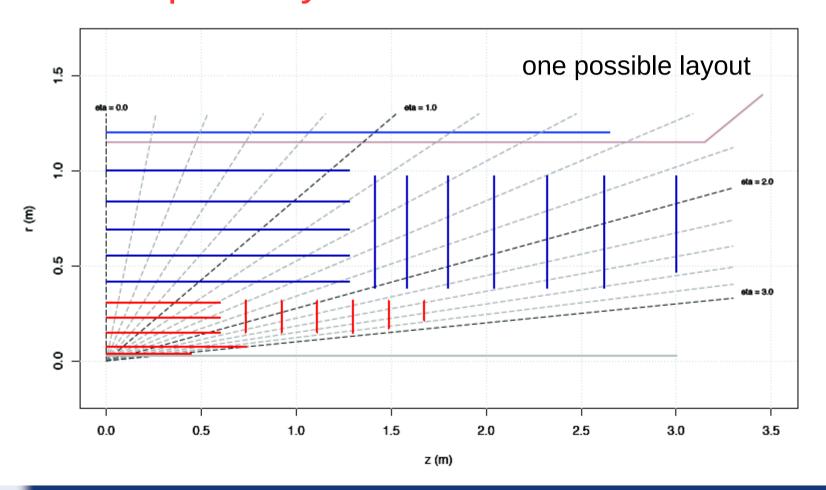


- Introduction
- Module development:
  - New FE Chip
  - Sensor developments: planar, 3D, diamond, CMOS
- Read-out:
  - Triggering aspects & data transmission
  - Possible read-out scenario
- Mechanics

- ATLAS phase2-upgrade: complete re-design of inner tracking system for HL-LHC operation
  - Most of current detector not suitable for HL-LHC
  - Goal: maintain or improve tracking efficiency and small fake rate + b-tagging capabilities
  - Several challenges:
    - Higher track density
    - Higher irradiation dose, fluence
    - Higher hit rates
      → all silicon detector
    - Re-design of triggering system



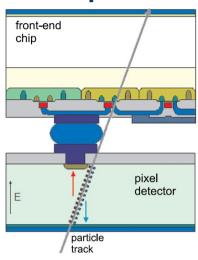
- Plans for new "inner tracker" (ITK) taking shape
- New layout: all-silicon with outer strip layers and inner pixel layers



- Plans for new "inner tracker" (ITK) taking shape
- New layout: all-silicon with outer strip layers and inner pixel layers — this talk
  - Pixel activities started to ramp up this year
  - Benefiting from 1<sup>st</sup> upgrade (insertable b-layer, IBL) that just completed:
    - Already had a re-design of the read-out (FE, off-det.)
    - Considered and used new sensor concepts:
      - 3D in outer layers of IBL (inner: planar sensors)
      - Diamond sensors in IBL-style diamond beam monitor (DBM)
    - Improved mechanics/cooling concepts

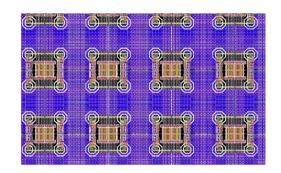


- Modules: use well-established hybrid concept
  - Sensors:
    - Planar-, 3D-silicon, diamond
    - New concept: CMOS, combined with hybrid r/o
  - FE chip: new design for all pixel layers (unclear availability of foundry that produced IBL FE)
- In any case, many improvements needed:
  - Increased radiation hardness
  - Smaller pixels
  - Efficiency improvements in sensor design
  - Low(er)-cost interconnect technology

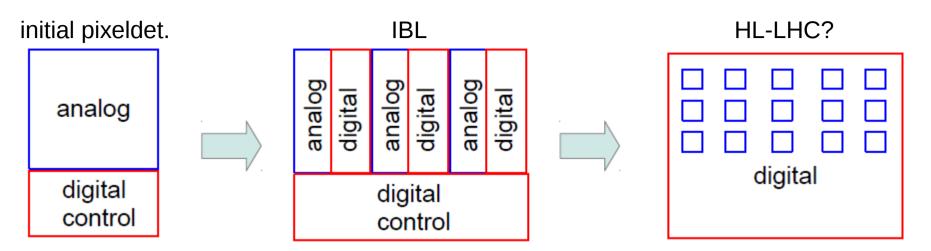




- Expected design specifications for FE chip:
  - Format, power similar to IBL FE
  - Pixel size:
    - Hit rate estimate: 2 GHz/cm<sup>2</sup>
    - Preserve 50µm spacing between bumps
    - 2500 μm² pixel area: needs a recovery time of 200ns → larger area not feasible (squared 50x50 μm²?)
  - Trigger rate: 1MHz single level (+ safety margin)
    - This requires several Gbps output per chip
  - Many things are the same for ATLAS and CMS → collaboration via RD53



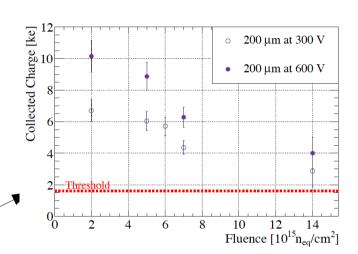
## ITK Pixel FE Chip (2)



- Need improvement in digital/analog isolation (50kHz firing rate for  $50x50 \mu m^2$  pixel)
- Combined with low threshold (IBL: ~1000e possible): very challenging
- Check radiation hardness of new 130nm or 65nm vendors:
  - Target: 1 GRad
  - Qualification studies with 3 vendors on-going, but much more to do
- Design changes needed for high output rate



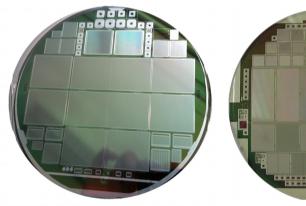
- Planar sensors (mostly n-in-p, also n-in-n)
  - Good candidate for outer layers: larger areas
  - Usage for inner layers: radiation hardness?
    - Charge collection studies done after irrad. to  $\sim 10^{16} n_{eq} cm^{-2}$



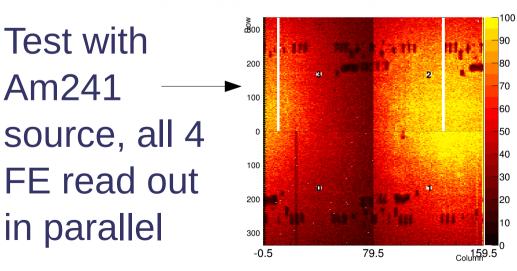
- Other aspects investigated:
  - Better efficiency with active edge sensors
  - Thin sensors (<200 μm)</li>
  - Pixel capacitance: small enough for FE?
  - Improve biasing structures (know ineff. from past)

## ITK Pixel Sensors (planar-quad)

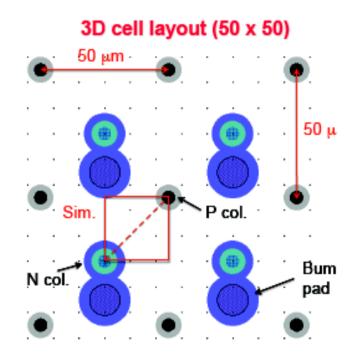
- 2x2 FE modules built with planar sensors
  - Aim: reduce bump bond cost (scales per module)
  - Starting from IBL design: 2x 2-FE-sensor
  - Helps to build electrically functional quad-modules
  - Flexes designed for these modules, bump bond tests







- 3D-sensors: driven by IBL vendors (CNM, FBK)
- Option for inner layers: adapt IBL design for new geometry and thickness
  - Smaller pixel size requires thinner sensors to take advantage of the high pixel spatial resolution
  - Radiation hardness: smaller inter-electrode spacing
  - Slim or active edges
  - Must tune pixel capacitance to meet FE requirements

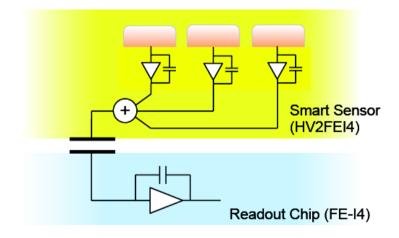




- Diamond also option for inner layers
  - Fluence >10<sup>16</sup>n<sub>eq</sub>cm<sup>-2</sup>: acceptable signal degradation
  - Stable operation at low thresholds (1000e or lower)
  - Sensor supply for 1-2 m<sup>2</sup> should be possible
- Vendor availability? Many produce pCVD but few at sensor quality
- Debug the bump-bonding issues from DBM
- Thinner sensors,
  3D-diamond, ...



- HV/HR-CMOS: combine with hybrid concept
  - Use recent developments on CMOS "smart diodes"
  - Attach to "regular" FE chip for full read-out features
- Example: HV2FEI4 CMOS on IBL FE:
  - Combined operation possible
  - Used in src tests, testbeam
- Interconnect: bump bonds, gluing, TSV,...?



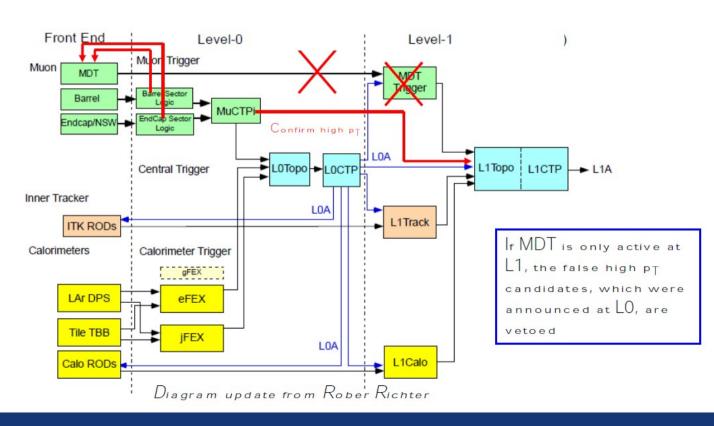
 Starting demonstrator project to evaluate if suitable for ATLAS



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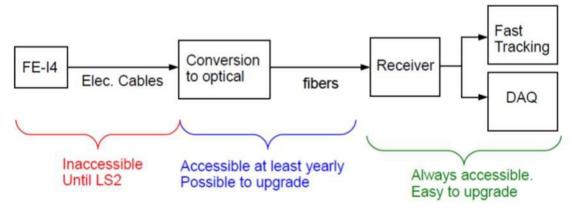
- HL-LHC will see a new L0 trigger in ATLAS partial/full read-out:
  - L0 : 1 MHz 6 μs latency
  - L1: 400 KHz 24 μs latency
  - Pixel will do full readout on L0



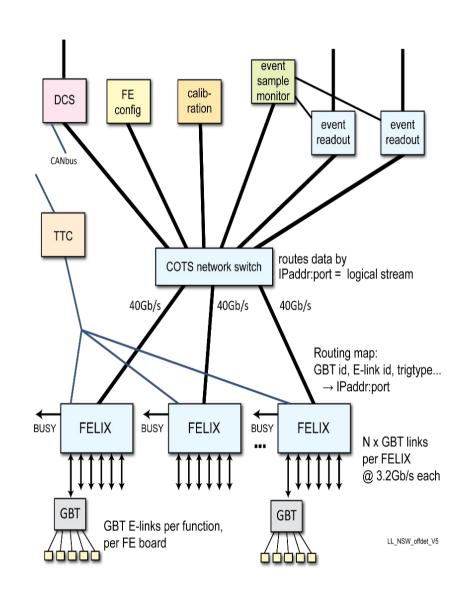
## Data rates and bandwidths at 1MHz trigger:

Detector	Number of	Module type	Rate/module	GBT/stave	Rate/GBT	Link per
	modules per		[Mb/s]	side	[Mb/s]	$\operatorname{side}$
	stave/disk					
layer 1	22	dual	5120	11	5120	176
layer 2	36	quad	5120	18	5120	288
layer 3	35	quad	2560	9	5120	288
layer 4	35	quad	1280	5	5120	260

- Data links:
  - Prefer to move opto comp. outside of det.volume: fast electrical cables
  - Then via fast optical links: GBT fast enough?



- Then, general ATLAS concept:
  - data routed via switch
- Pixels: use DAQ HW also for calibration
  - Goes beyond pure data transport needs
  - Address scan control and data decoding (histogram) apects



- Developments on support structures
  - Example: Stavelets = shorter staves



More dynamical layout, e.g. Alpine

 Stave profile changes along longitud. direction, modules attached to inclined support

- HL-LHC ATLAS-Pixel development is picking up speed with more details under investigation
- Many challenges ahead:
  - New FE design with new technology
  - Decide on best sensor technology(ies?)
  - Many new aspects beyond module design: readout, mechanics,...

Schedule: "technical design review" in 2017